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7/7/03
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Docket No.: 60188-431

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



In the Application of
Akihiko ISHIBASHI, et al.

Serial No.: 10/017,389 : Group Art Unit: 2818

Filed: December 18, 2001 : Examiner: TRAN, MAI HUONG C.

For: METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING DEVICE

PETITION FOR EXTENSION OF TIME

Mail Stop Extension of Time
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

It is respectfully requested that the time for response to the Office Action dated March 20, 2003, now due to expire April 20, 2003, be extended for two month(s) and set to expire on June 20, 2003.

Please charge the extension fee of \$410.00 to Deposit Account No. 500417. Please charge any additional fees or credit any overpayment to Deposit Account No. 500417.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

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Date: June 20, 2003